

# *AOZ8S516UDS-05*

Single Channel High Surge TVS

## **General Description**

The AOZ8S516UDS-05 is a single channel high power transient voltage suppressor designed to protect power line from damaging surge and ESD events, with an operating voltage of 5V.

This device is with one unidirectional TVS diode in 1.6x1.0 mm DFN package. It may apply to meet the IEC61000-4-5 surge immunity and IEC61000-4-2 ESD immunity requirements.

The AOZ8S516UDS comes in a RoHS compliant and Halogen Free 1.6mm x 1.0mm x 0.5mm package and is rated for  $-40^{\circ}$ C to  $+125^{\circ}$ C junction temperature range.

#### **Features**

- Surge protection for power rail
- IEC 61000-4-5 8/20 µs: 100 A
- IEC 61000-4-2 (ESD): ±30kV (Air and Contact)
- Human body mode (HBM): ±8kV
- IEC 61000-4-4 (EFT): 80A (5/50ns)
- Peak pulse power: 1050W
- Operating voltage: 5V
- Green product

#### **Applications**

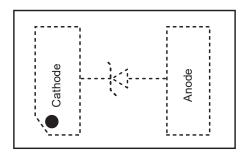
- PD3.0/PD3.1 VBUS
- Power lines
- Panel
- Mobile phone
- Notebook computers



# **Typical Application**

# Power Line

### **Pin Configuration**



DFN1.6x1.0-2L



# **Ordering Information**

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8S516UDS-05	-40°C to +125°C	DFN1.6 x 1.0-2L	Green Product



AOS products are offered in packages with Pb-free plating and compliant to RoHS standards.

Please visit https://aosmd.com/sites/default/files/media/AOSGreenPolicy.pdf for additional information.

### **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
VP-VN	5V
Peak Pulse Current (I <sub>PP</sub> ), t <sub>P</sub> = 8/20 µs	100A
Peak Pulse Power (P <sub>PP</sub> ), t <sub>P</sub> = 8/20 µs	1050W
Storage Temperature (T <sub>S</sub> )	-65°C to +150°C
EFT Rating per IEC61000-4-2, Contact <sup>(1)</sup>	±30kV
ESD Rating per IEC61000-4-2, Air <sup>(1)</sup>	±30kV
ESD Rating per Human Body Model <sup>(2)</sup>	±8kV

#### Notes:

- 1. IEC 61000-4-2 discharge with  $C_{Discharge}$  = 150 pF,  $R_{Discharge}$  = 330  $\Omega$ .
- 2. Human Body Discharge per MIL-STD-883, Method 3015  $C_{Discharge}$  = 100pF,  $R_{Discharge}$  = 1.5k $\Omega$ .

#### **Maximum Operating Conditions**

The device is not guaranteed to operate beyond the Maximum Operating Conditions.

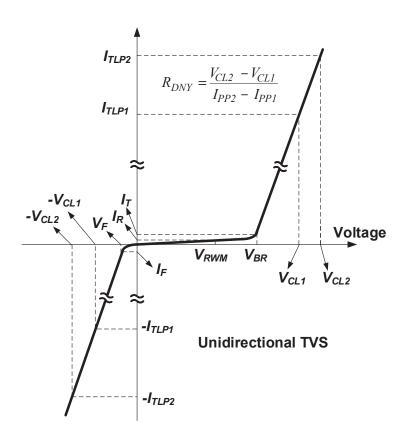
Parameter	Rating		
Junction Temperature (T <sub>J</sub> )	-40°C to +125°C		

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#### **Electrical Characteristics**

T<sub>A</sub> = 25°C, unless otherwise specified. Pin 2 as ground.



Symbol	Parameter	Conditions	Min	Тур	Max	Units
$V_{RWM}$	Reverse Working Voltage	I/O Pin-to-Ground			5	V
$V_{BR}$	Reverse Breakdown Voltage	$I_T$ = 1mA, I/O Pin-to-Ground	6	7	8.5	V
I <sub>R</sub>	Reverse Leakage Current	Max. V <sub>RWM,</sub> I/O Pin-to-Ground		10	100	nA
$V_{F}$	Forward Voltage	I <sub>F</sub> = 15mA		0.75	1.0	V
$V_{\text{CL}}$	Clamping Voltage <sup>(3)(4)</sup> (100ns Transmission Line Pulse, I/O Pin to GND)	I <sub>TLP</sub> = 1 A I <sub>TLP</sub> = -1 A		7.1 -0.9		V
		$I_{TLP} = 30 A$ $I_{TLP} = -30 A$		7.7 -1.6		
	Clamping Voltage <sup>(3)</sup> (IEC61000-4-5, Surge 8/20µs)	I <sub>PP</sub> = 5A I <sub>PP</sub> = -5A		7.2 -1.1		
		I <sub>PP</sub> = 100 A I <sub>PP</sub> = -100 A		10.3 -3.6		
R <sub>DNY</sub>	Dynamic Resistance <sup>(3)(4)</sup>	$I_{TLP} = 1A \text{ to } 3A$ $I_{TLP} = -1A \text{ to } 30A$		0.02 0.02		Ω
CJ	Junction Capacitance <sup>(3)</sup>	V <sub>I/O</sub> = 0V, f = 1MHz		850		pF

#### Notes:

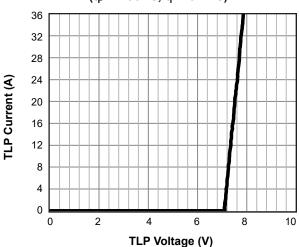
- 3. These specifications are guaranteed by design and characterization.
- 4. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.

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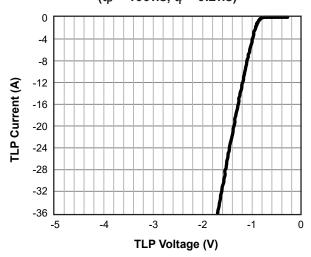


# **Typical Characteristics**

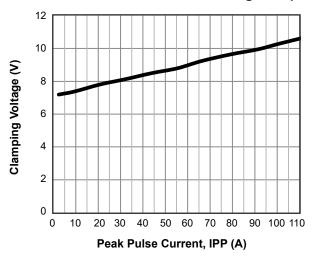
Positive Transmission Line Pulse  $(t_P = 100 \text{ ns}, t_r = 0.2 \text{ ns})$ 



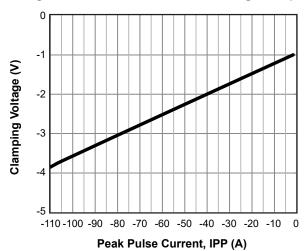
Negative Transmission Line Pulse  $(t_P = 100 \text{ ns}, t_r = 0.2 \text{ ns})$ 



Positive Curve of IEC61000-4-5 Surge 8/20µs



Negative Curve of IEC61000-4-5 Surge 8/20µs





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2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.